

SANYO Semiconductors DATA SHEET

Bi-CMOS IC

LV5818M

Step-down Switching Regulator

Overview

LV5818M is a 1ch step-down switching regulator. 0.3Ω FET is incorporated on the upper side to achieve high-efficiency operation for large output current. Low-heat resistance and compact-package MFP12 employed. Current mode control type, with superior load current response and easy phase compensation EN pin, allowing the standby mode with the current drain of 70μ A or less Pulse-by-pulse over-current protection and overheat protection available for protection of load devices Soft start pin to be provided with a capacitance for soft start.

Functions

- 2A 1ch step-down switching regulator
- Wide input dynamic range (to 28V)
- High efficiency (90% $I_{OUT} = 1A$, $V_{IN} = 12V$, $V_O = 5V$)
- Standby mode
- Over-current protection
- External synchronous driving

- Thermal shutdown
- Reference voltage: 0.8V
- The frequency is changeable in external resistance.
- Soft start
- Compact package: MFP12

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum input V _{IN} voltage	V _{IN} max		32	V
BOOT pin maximum voltage	V _{BT} max		37	V
SW pin maximum voltage	V _{SW} max		V _{IN} max	V
BOOT pin-SW pin maximum voltage	V _{BS-SW} max		7	V
FB, EN, COMP, SS, SYNC, RT pin	Vfs max		7	V
maximum voltage				
Allowable power dissipation	Pd max	Mount on a specified board *	1.65	W
Junction temperature	Tj max		150	°C
Operating temperature	Topr		-20 to 80	°C
Storage temperature	Tstg		-40 to 150	°C

^{*} Specified board: 46.4mm × 31.8mm ×1.7mm, glass epoxy both side.

Note: Plan the maximum voltage while including coil and surge voltages, so that the maximum voltage is not exceeded even for an instant.

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Recommended Operating Conditions at Ta = 25°C

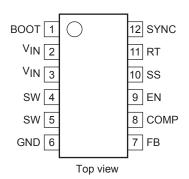
Parameter	Symbol	Conditions	Ratings	Unit
V _{IN} pin voltage	V _{IN}		8 to 28	V
BOOT pin voltage	V _{BT}		-0.3 to 34	V
SW pin voltage	V _{SW}		-0.4 to V _{IN}	V
BOOT pin-SW pin maximum voltage	V _{BS-SW}		6.5	V
FB, EN, COMP, SS, SYNC, RT pin voltage	V _{FSO}		6	V
Operating frequency	Fosc		60k to 1M	Hz

Electrical Characteristics at Ta = 25°C, $V_{IN} = 12$ V, unless otherwise specified.

Devenueles	Symbol	Conditions	Ratings			11.2
Parameter			min	typ	max	Unit
IC current drain at standby	I _{CC} 1	EN=0V		70		μΑ
IC current drain in operation	I _{CC} 2	EN=OPEN		5		mA
Efficiency	Effcy	V_{IN} =12V, I_{OUT} =1A, Vo=5V, RT=100kΩ Design target *1		90		%
Reference voltage	Vref	V _{IN} =8V to 28V (±2%)	-2%	0.8	+2%	V
FB pin bias current	Iref	FB=0.8V application		10	100	nA
High-side ON resistance	RonH	BOOT=5V		0.3		Ω
Low-side ON resistance	RonL			6		Ω
Oscillation frequency	fosc	RT=100kΩ	290	325	360	kHz
Oscillation frequency during short-circuit protection	foscs	RT=100kΩ	48	60	72	kHz
EN high-threshold voltage	Venh				1.9	V
EN low-threshold voltage	VenI		0.8			V
EN pull up current	l _{en}	EN = 0V		16		μА
SYNC pin threshold High-voltage	VsyncH				2.6	V
SYNC pin threshold Low-voltage	VsyncL		0.8			V
Maximum ON DUTY	D max			80		%
Current limit peak value	Icl1	V _{IN} =12V, V _{OUT} =5V, L=10μH	3			Α
Thermal shutdown temperature	Ttsd	*Design guarantee *2		160		°C
Thermal shutdown temperature hysteresis	Dtsd	*Design guarantee *2		40		°C
Soft start current	Iss	SS=0V	6	10	14	μΑ

^{*1:} Reference value (not tested before shipment)

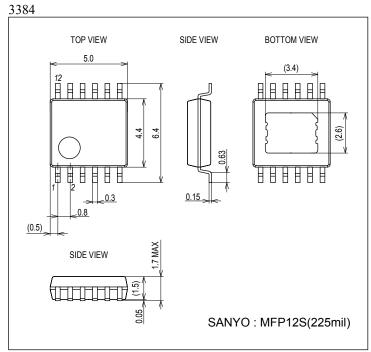
Pin Assignment

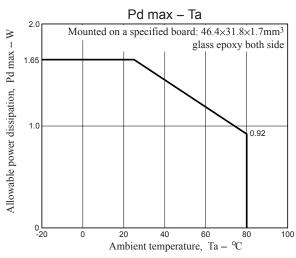


^{*2:} Design guarantee (value guaranteed by design and not tested before shipment)

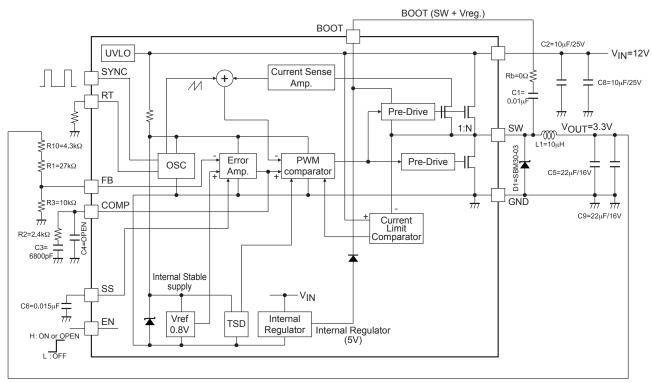
Package Dimensions

unit: mm (typ)





Block Diagram and Sample Application Circuit (3.3V output)



C1,C8,C5,C9 = Ceramic capacitor L1 = CDRH105RNP-100NC (sumida)

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Pin Function

Pin No.	Pin name	Function	Equivalent circuit
1	BOOT	Upper MOS transistor boot strap capacitance connection pin. Connect the boot capacitance of about $0.01\mu F$ between SW pins. To protect the SW pin's absolute maximum rating, to ensure stable operation, and to eliminate noise, the boot capacitance serial resistance (about 10Ω) Rb proves effective.	VIN BOOT
2,3	V _{IN}	Input voltage pin. Connect substantially large (20 μF more) capacitance between this pin and GND.	Hi side MOS
4,5	SW	Power switch pin. Connect the output LC filter. Connect the above capacitance between this pin and BOOT pin.	SW Low side MOS
6	GND	Ground pin.	
7	FB	Feedback pin. Sets the output voltage by means of split resistor in the section of the output voltage V_{OUT} - FB - GND. V_{OUT} setting is made as calculated below: $V_{OUT} = Vref \times \left\{1 + \frac{(R1 + R10)}{R3}\right\}$ $Vref = 0.8V$ Example: 3.3V output voltage (See Block Diagram and Sample Application Circuit) $V_{OUT} = 0.8 \times \left\{1 + \frac{(27k + 4.3k)}{10k}\right\}$ = 3.304V	VIN internal regulation line
10	SS	Soft start pin. Sets the soft start time by means of the built-in $10\mu A$ source voltage and external soft start capacity. The soft start capacity C6 can be set as follows: $C6 = 10\mu A \times \frac{Tss}{Vref}$ Where, Tss is the soft start time and Vref is the reference voltage. Example: 1.2ms soft start time achieved $C6 = 10\mu A \times \frac{1.2ms}{0.8 \text{ V}} = 0.015\mu F$	SS W FB
8	COMP	Phase compensation pin. Connects with the phase compensation external capacitance and resistance of DC/DC converter close loop.	VIN internal reguration line COMP
7	EN	Enable pin. Converter enabled when set to the HIGH voltage and disabled when LOW voltage or OPEN state.	VIN

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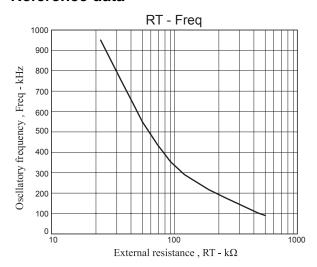
Pin No.	Pin name	Function	Equivalent circuit
11	RT	RT pin. To set the frequency, resistance is connected.	VIN MIN MIN MIN MIN MIN MIN MIN MIN MIN M
12	SYNC	SYNC pin. The external cycle clock is impressed.	SYNC

Considerations for the design

you use the external cycle function.

Insertion of serial beads in the Schottky diode for removal of noise may cause generation of the negative voltage deviating from the absolute maximum rating at the SW pin, resulting in failure of normal operation. In such an event, do not insert beads as above described and, instead, remove noise by means of the BOOT resistance Rb. Please set the internal frequency decided by the terminal RT about 50kHz lower than an external input frequency when

Reference data



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